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June 2003

FDS6990A

FAIRCHILD

Dual N-Channel Logic Level PowerTrench^o MOSFET

General Description

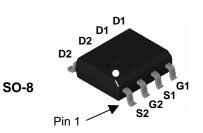
These N-Channel Logic Level MOSFETs are produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance.

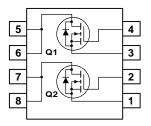
These devices are well suited for low voltage and battery powered applications where low in-line power loss and fast switching are required.

Features

• 7.5 A, 30 V.
$$\begin{array}{l} {\sf R}_{\sf DS(ON)} = 18 \mbox{ m}\Omega \enskip 0 \mbox{ V}_{\sf GS} = 10 \mbox{ V} \\ {\sf R}_{\sf DS(ON)} = 23 \mbox{ m}\Omega \enskip 0 \mbox{ V}_{\sf GS} = 4.5 \mbox{ V} \end{array}$$

- Fast switching speed
- Low gate charge
- High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$
- High power and current handling capability





Absolute Maximum Ratings T_{A=25°C} unless otherwise noted

Symbol	Parameter			Ratings	Units	
V _{DSS}	Drain-Sour	Source Voltage		30	V	
V _{GSS}	Gate-Source	e Voltage		± 20	V	
I _D	Drain Current – Continuous (Note 1a)		7.5	А		
		– Pulsed		20		
P _D	Power Dissipation for Single Operation		tion (Note 1a)	1.6	W	
			(Note 1b)	1.0		
			(Note 1c)	0.9		
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C	
Therma	l Charac				°C/W	
R _{θJA}	Thermal Re	esistance, Junction-to-Ar	nbient (Note 1a)	78		
R _{θJC}	Thermal Re	esistance, Junction-to-Ca	40	°C/W		
Packag	e Markin	g and Ordering	Information			
Device Marking		Device	Reel Size	Tape width	Quantity	
FDS6990A		FDS6990A	13"	12mm	2500 units	

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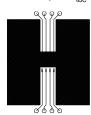
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 V$, $I_D = 250 \mu A$	30			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		26		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current				1 10	μΑ
I _{GSS}	Gate–Source Leakage	$V_{GS}=\pm 20~V,~V_{DS}=0~V$			±100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	1	1.9	3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu A$, Referenced to $25^{\circ}C$		-4		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance	$ \begin{array}{c} V_{GS} = 10 \ V, I_D = 7.5 \ A \\ V_{GS} = 4.5 \ V, I_D = 6.5 \ A \\ V_{GS} = 10 \ V, \ I_D = 7.5 \ A, T_J = 125^\circ C \end{array} $		11 13 15	18 23 31	mΩ
I _{D(on)}	On–State Drain Current	$V_{GS} = 10 \text{ V}, V_{DS} = 5 \text{ V}$	20			Α
g fs	Forward Transconductance	$V_{\text{DS}} = 5 \text{ V}, \qquad I_{\text{D}} = 7.5 \text{ A}$		33		S
Dynamic	c Characteristics					
Ciss	Input Capacitance	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V},$		1235		pF
Coss	Output Capacitance	f = 1.0 MHz		295		pF
C _{rss}	Reverse Transfer Capacitance			120		pF
R _G	Gate Resistance	V _{GS} = 15 mV, f = 1.0 MHz		2.3		Ω
Switchin	g Characteristics (Note 2)					
t _{d(on)}	Turn–On Delay Time	$V_{DD} = 15 \text{ V}, I_D = 1 \text{ A},$		10	19	ns
t _r	Turn–On Rise Time	$V_{GS} = 10 \text{ V}, R_{GEN} = 6 \Omega$		5	10	ns
t _{d(off)}	Turn–Off Delay Time			28	44	ns
t _f	Turn–Off Fall Time			10	19	ns
Q _g	Total Gate Charge	$V_{DS} = 15 V$, $I_D = 7.5 A$,		12	17	nC
Q _{gs}	Gate-Source Charge	$V_{GS} = 5 V$		3.5		nC
Q _{gd}	Gate-Drain Charge			4.2		nC
Drain-S	ource Diode Characteristics	and Maximum Ratings				
ls	Maximum Continuous Drain-Source				1.3	А
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$, $I_S = 1.3 A$ (Note 2)		0.7	1.2	V
4	Diada Davana Daarvan Tima			24		20

Qrr Notes:

trr

1. R_{0,JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $\rm R_{\theta JC}$ is guaranteed by design while $\rm R_{\theta CA}$ is determined by the user's board design.

 $I_F = 7.5 \text{ A}, \quad d_{iF}/d_t = 100 \text{ A}/\mu \text{s}$



a) 78°C/W when mounted on a 0.5in² pad of 2 oz copper

Diode Reverse Recovery Time

Diode Reverse Recovery Charge



b) 125°C/W when mounted on a 0.02 in² pad of 2 oz copper c) 135°C/W when mounted on a minimum mounting pad.

24

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Scale 1:1 on letter size paper

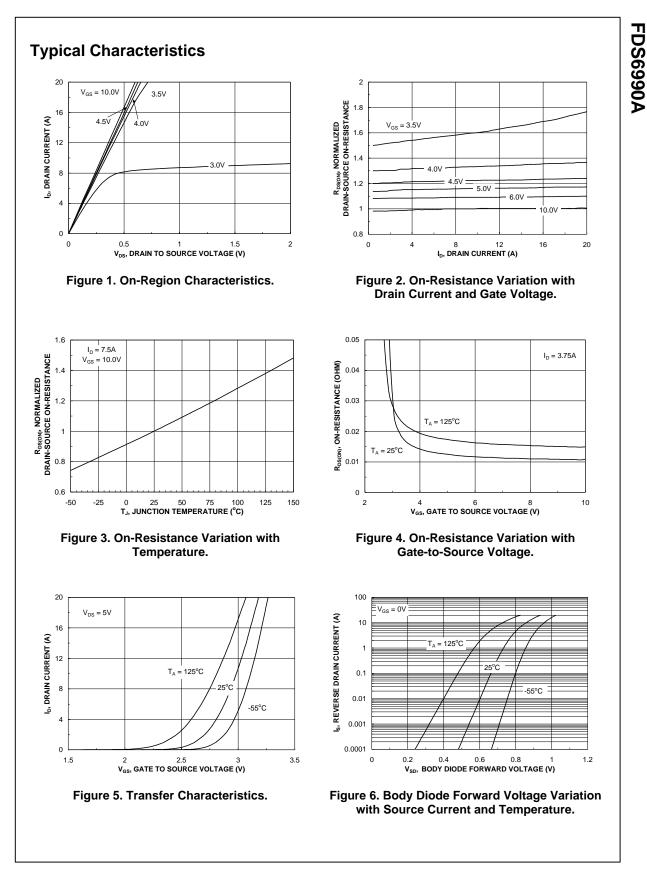
Pulse Test: Pulse Width < 300µs, Duty Cycle < 2.0%

FDS6990A Rev D(W)

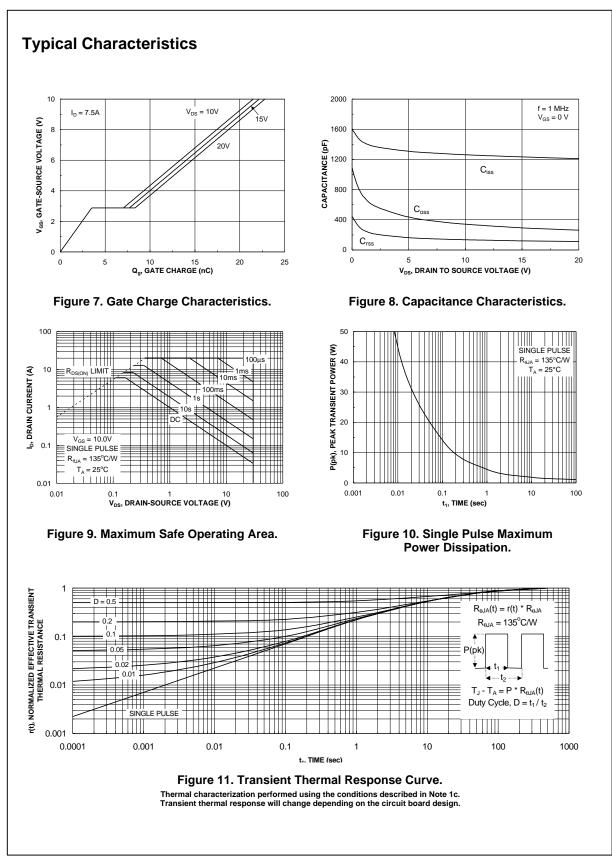
nS

nC

FDS6990A



FDS6990A Rev D(W)



FDS6990A

FDS6990A Rev D(W)

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